



### **60V P-Channel Enhancement Mode MOSFET**

Voltage

-60 V

Current

-15 A

#### **Features**

- $R_{DS(ON)}$ ,  $V_{GS}$ @-10V, $I_{D}$ @-7.5A<68 $m\Omega$
- $R_{DS(ON)}$ ,  $V_{GS}$ @-4.5V, $I_D$ @-4.0A<85 $m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

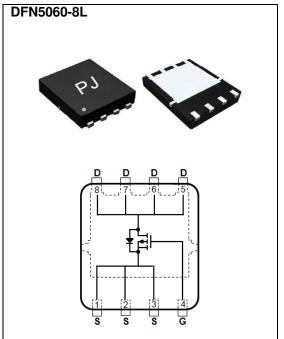
### **Mechanical Data**

• Case: DFN5060-8L Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0028 ounces, 0.08 grams

Marking: Q5463A



### Maximum Ratings and Thermal Characteristics (T<sub>A</sub>=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		$V_{DS}$	-60	V	
Gate-Source Voltage		$V_{GS}$	<u>+</u> 20	V	
Continuous Drain Current	T <sub>C</sub> =25°C	l <sub>D</sub>	-15	А	
	T <sub>C</sub> =100°C		-9.5		
Pulsed Drain Current (Note 1)	T <sub>C</sub> =25°C	I <sub>DM</sub>	-60	İ	
Power Dissipation	T <sub>C</sub> =25°C	Po	25	W	
	T <sub>C</sub> =100°C		10		
Continuous Drain Current	T <sub>A</sub> =25°C	I <sub>D</sub>	-4.0	Α	
	T <sub>A</sub> =70°C		-3.2	Α	
Power Dissipation	T <sub>A</sub> =25°C	-	2.0	W	
Power Dissipation	T <sub>A</sub> =70°C	Po	1.3		
Single Pulse Avalanche Energy (Note 6)		E <sub>AS</sub>	31	mJ	
Operating Junction and Storage Temperature Range		$T_J, T_{STG}$	-55~150	°C	
Typical Thermal Resistance (Note 4,5)	Junction to Case	R <sub>eJC</sub>	5.0	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature





### **Electrical Characteristics** (T<sub>A</sub>=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}$ =0V, $I_D$ =-250uA	-60	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$ , $I_{D}=-250$ uA	-1.0	-1.63	-2.5	V	
Drain-Source On-State Resistance	R <sub>DS(on)</sub>	V <sub>GS</sub> =-10V,I <sub>D</sub> =-7.5A	-	55	68	mΩ	
		V <sub>GS</sub> =-4.5V,I <sub>D</sub> =-4.0A	-	73	85	11177	
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}$ =-60V, $V_{GS}$ =0V	-	-	-1.0	uA	
Gate-Source Leakage Current	$I_{GSS}$	V <sub>GS</sub> = <u>+</u> 20V,V <sub>DS</sub> =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 7)							
Total Gate Charge	$Q_g$	V <sub>DS</sub> =-30V, I <sub>D</sub> =-7.5A, V <sub>GS</sub> =-10V <sup>(Note 3)</sup>	-	17	-	nC	
Gate-Source Charge	$Q_gs$		-	2.8	-		
Gate-Drain Charge	$Q_gd$	V <sub>GS</sub> =-10V	-	3.6	-		
Input Capacitance	Ciss	V <sub>DS</sub> =-30V, V <sub>GS</sub> =0V, f=1.0MHZ	-	879	-	pF	
Output Capacitance	Coss		-	70	-		
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	47	-		
Turn-On Delay Time	td <sub>(on)</sub>	\/ 00\/   4A	-	8.4	-		
Turn-On Rise Time	t <sub>r</sub>	$V_{DD}$ =-30V, $I_{D}$ =-1A, $V_{GS}$ =-10V, $R_{G}$ =6 $\Omega$ (Note 3)	-	30	-	ns	
Turn-Off Delay Time	td <sub>(off)</sub>		-	52	-		
Turn-Off Fall Time	t <sub>f</sub>		-	16	-		
Drain-Source Diode							
Maximum Continuous Drain-Source					-15	Α	
Diode Forward Current	I <sub>S</sub>		-	-	-13	A	
Diode Forward Voltage	$V_{SD}$	I <sub>S</sub> =1A,V <sub>GS</sub> =0V	-	-0.73	-1.0	V	

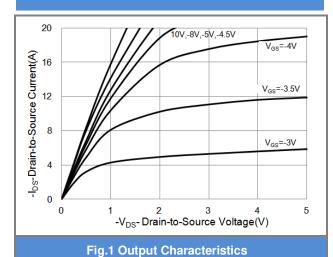
#### NOTES:

- 1. Pulse width<a></a>300us, Duty cycle<a></a>2%
- 2. Essentially independent of operating temperature typical characteristics.
- 3. Repetitive rating, pulse width limited by junction temperature TJ(MAX)=150°C. Ratings are based on low frequency and duty cycles to keep initial TJ =25°C.
- 4. The maximum current rating is package limited.
- 5. Rejah is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch<sup>2</sup> with 2oz.square pad of copper.
- 6. The test condition is L=0.1mH,  $I_{AS}$ =25A,  $V_{DD}$ =25V,  $V_{GS}$ =10V
- 7. Guaranteed by design, not subject to production testing.





### **TYPICAL CHARACTERISTIC CURVES**



-V<sub>GS</sub>-Gate-to-Source Voltage(V)

**Fig.2 Transfer Characteristics** 

T<sub>J</sub>=125℃

T<sub>J</sub>=25°C

20

16

8

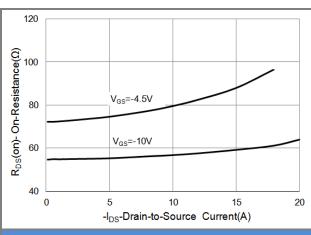
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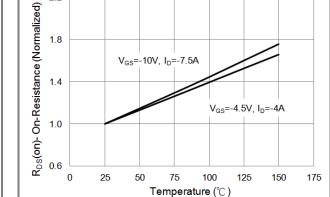
2.2

1.8

-IDS-Drain-to-S ource Current(A)

 $V_{DS} = -5V$ 

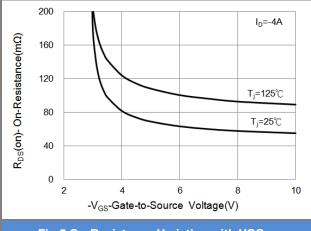




V<sub>GS</sub>=-10V, I<sub>D</sub>=-7.5A







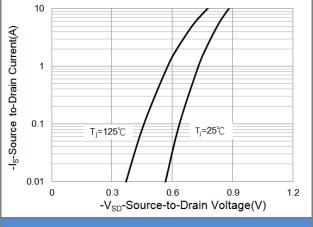


Fig.5 On-Resistance Variation with VGS. Fig.6 Source-Drain Diode Forward Voltage





### **TYPICAL CHARACTERISTIC CURVES**

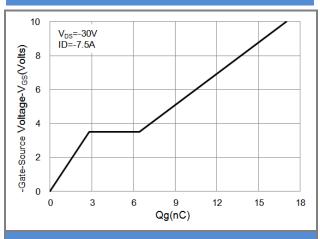


Fig.7 Gate-Charge Characteristics

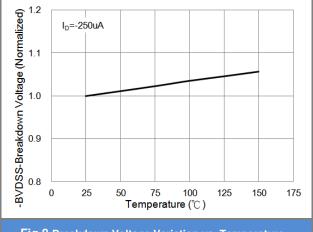


Fig.8 Breakdown Voltage Variation vs. Temperature

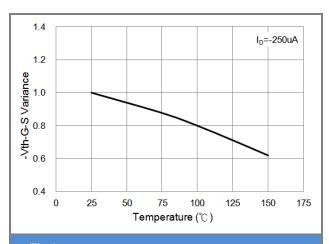


Fig.9 Threshold Voltage Variation with Temperature

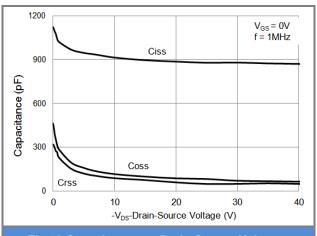
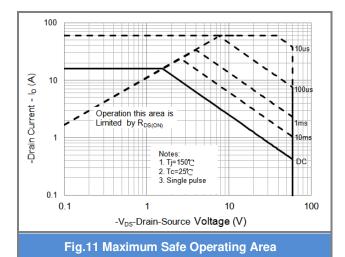


Fig.10 Capacitance vs. Drain-Source Voltage







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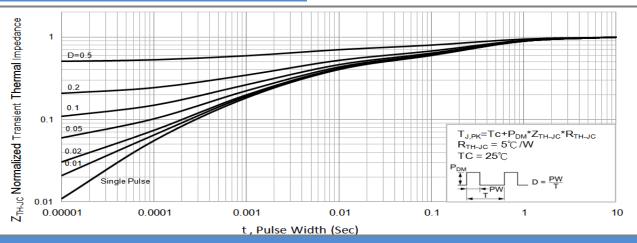


Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

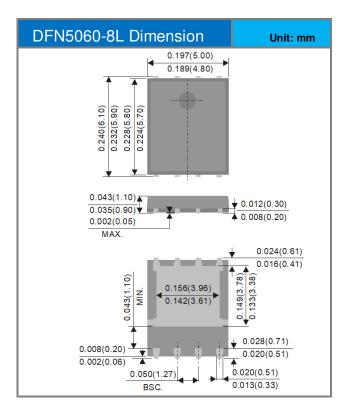


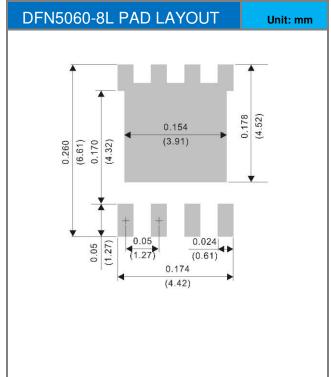


### PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version	
PJQ5463A_R2_00001	DFN5060-8L	3000pcs / 13" reel	Q5463A	Halogen free	

### **Packaging Information & Mounting Pad Layout**









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